NSN 5961-01-201-6401

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-201-6401 **Inclosure Material:** Metal **Overall Length:** 1.453 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-5 **Mounting Method:** Threaded stud Features Provided: Hermetically sealed case and reverse polarity **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 70.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 140.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab w/wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No